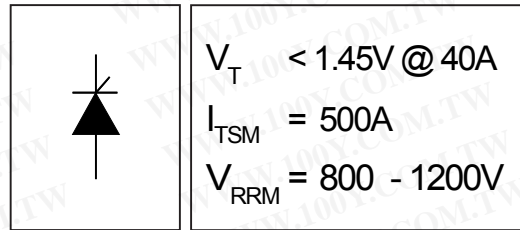


International IR Rectifier

SAFEIR Series 40TPS..

PHASE CONTROL SCR



Description/ Features

The 40TPS... **SAFEIR** series of silicon controlled rectifiers are specifically designed for medium power switching and phase control applications. The glass passivation technology used has reliable operation up to 125°C junction temperature. Low Igt parts available.

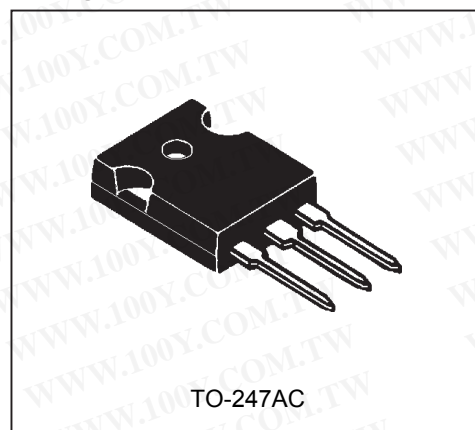
Typical applications are in input rectification (soft start) and these products are designed to be used with International Rectifier input diodes, switches and output rectifiers which are available in identical package outlines.

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 勝特力电子(深圳) 86-755-83298787
[Http://www.100y.com.tw](http://www.100y.com.tw)

Major Ratings and Characteristics

Characteristics	40TPS..	Units
$I_{T(AV)}$ Sinusoidal waveform	35	A
I_{RMS}	55	A
V_{RRM}/V_{DRM} Range	800 - 1200	V
I_{TSM}	500	A
$V_T @ 40A, T_J = 25^\circ C$	1.45	V
dv/dt	1000	V/ μs
di/dt	100	A/ μs
T_J	-40 to 125	$^\circ C$

Package Outline



40TPS.. SAFEIR Series

Bulletin I2107 rev. G 09/03

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Voltage Ratings

Part Number	V_{RRM} / V_{DRM} , max. repetitive peak and off-state voltage V	V_{RSM} , maximum non repetitive peak reverse voltage V	I_{RRM} / I_{DRM} 125°C mA
40TPS08	800	900	10
40TPS12	1200	1300	

Absolute Maximum Ratings

Parameters	40TPS..	Units	Conditions	
$I_{T(AV)}$ Max. Average On-state Current	35	A	@ $T_C = 79^\circ\text{C}$, 180° conduction half sine wave	
$I_{T(RMS)}$ Max. Continuous RMS On-state Current As AC switch	55			
I_{TSM} Max. Peak One Cycle Non-Repetitive Surge Current	500	A	10ms Sine pulse, rated V_{RRM} applied	Initial $T_J = T_J \text{ max.}$
	600		10ms Sine pulse, no voltage reapplied	
I^2t Max. I^2t for Fusing	1250	A^2s	10ms Sine pulse, rated V_{RRM} applied	
	1760		10ms Sine pulse, no voltage reapplied	
$I^2\sqrt{t}$ Max. $I^2\sqrt{t}$ for Fusing	12500	$A^2\sqrt{s}$	t = 0.1 to 10ms, no voltage reapplied	
$V_{T(TO)1}$ Low Level Value of Threshold Voltage	1.02	V	$T_J = 125^\circ\text{C}$	
$V_{T(TO)2}$ High Level Value of Threshold Voltage	1.23			
r_{t1} Low Level Value of On-state Slope Resistance	9.74	$m\Omega$		
r_{t2} High Level Value of On-state Slope Resistance	7.50			
V_{TM} Max. Peak On-state Voltage	1.85	V	@ 110A, $T_J = 25^\circ\text{C}$	
di/dt Max. Rate of Rise of Turned-on Current	100	$A/\mu s$	$T_J = 25^\circ\text{C}$	
I_H Max. Holding Current	150	mA		
I_L Max. Latching Current	300			
I_{RRM} / I_{DRM} Max. Reverse and Direct Leakage Current	0.5	mA	$T_J = 25^\circ\text{C}$	$V_R = \text{rated } V_{RRM} / V_{DRM}$
	10		$T_J = 125^\circ\text{C}$	
dv/dt Max. Rate of Rise of Off-state Voltage	40TPS08	500	$V/\mu s$	$T_J = T_J \text{ max.}, \text{ linear to } 80\% V_{DRM}, R_g\text{-k} = \text{open}$
	40TPS12			

Triggering

Parameters	40TPS..	Units	Conditions	
P_{GM} Max. peak Gate Power	10	W		
$P_{G(AV)}$ Max. average Gate Power	2.5			
I_{GM} Max. peak Gate Current	2.5	A		
$-V_{GM}$ Max. peak negative Gate Voltage	10	V		
V_{GT} Max. required DC Gate Voltage to trigger	4.0		$T_J = -40^{\circ}C$	Anode supply = 6V resistive load
	2.5		$T_J = 25^{\circ}C$	
	1.7		$T_J = 125^{\circ}C$	
I_{GT} Max. required DC Gate Current to trigger	270	mA	$T_J = -40^{\circ}C$	
	150		$T_J = 25^{\circ}C$	
	80		$T_J = 125^{\circ}C$	
	40		$T_J = 25^{\circ}C$, for 40TPS08A and 40TPS12A	
V_{GD} Max. DC Gate Voltage not to trigger	0.25	V	$T_J = 125^{\circ}C$, $V_{DRM} = \text{rated value}$	
I_{GD} Max. DC Gate Current not to trigger	6	mA		

Thermal-Mechanical Specifications

Parameters	40TPS..	Units	Conditions	
T_J Max. Junction Temperature Range	-40 to 125	$^{\circ}C$		
T_{stg} Max. Storage Temperature Range	-40 to 125			
R_{thJC} Max. Thermal Resistance Junction to Case	0.6	$^{\circ}C/W$	DC operation	
R_{thJA} Max. Thermal Resistance Junction to Ambient	40			
R_{thCS} Max. Thermal Resistance Case to Heatsink	0.2		Mounting surface, smooth and greased	
wt Approximate Weight	6 (0.21)	g (oz.)		
T Mounting Torque	Min.	6 (5)	Kg-cm (lbf-in)	
	Max.	12 (10)		
Case Style	TO-247AC			

40TPS.. SAFEIR Series

Bulletin I2107 rev. G 09/03

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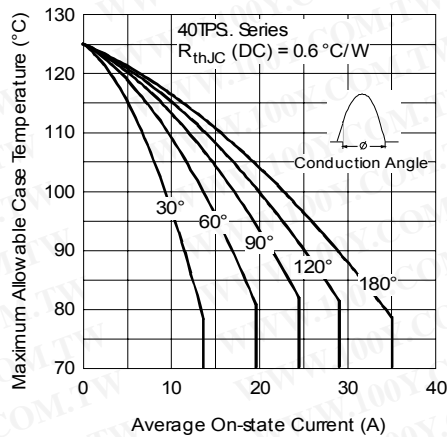


Fig. 1 - Current Rating Characteristics

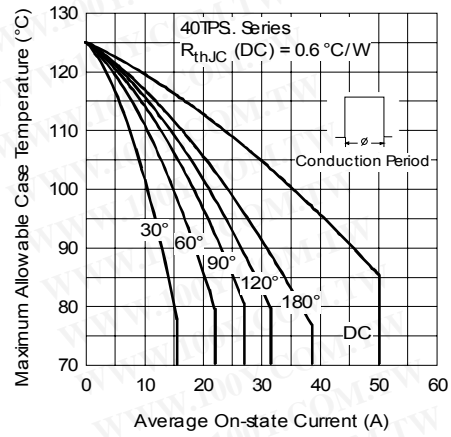


Fig. 2 - Current Rating Characteristics

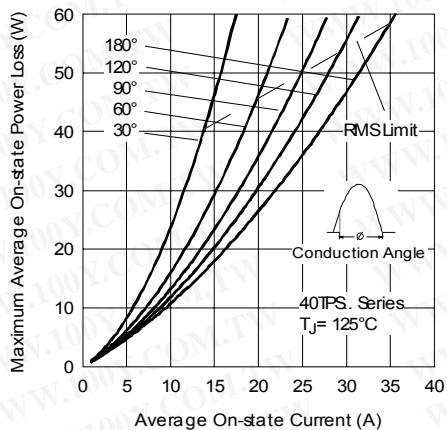


Fig. 3 - On-state Power Loss Characteristics

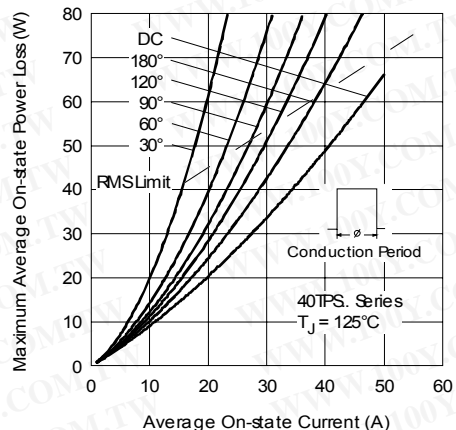


Fig. 4 - On-state Power Loss Characteristics

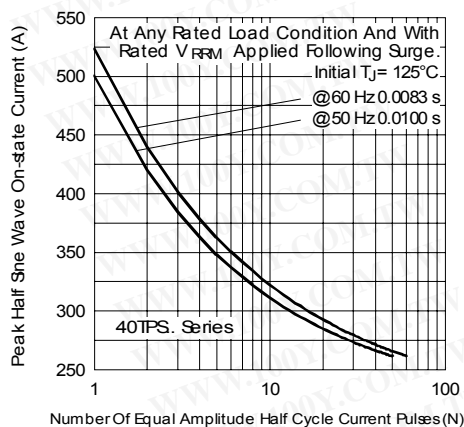


Fig. 5 - Maximum Non-Repetitive Surge Current

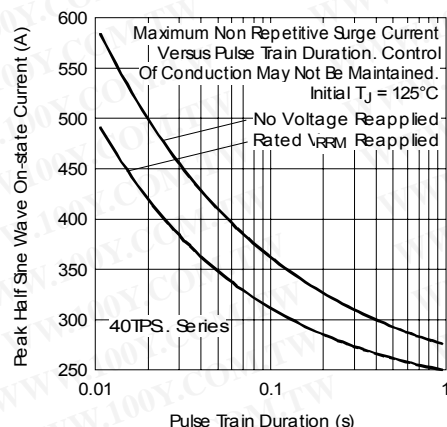


Fig. 6 - Maximum Non-Repetitive Surge Current

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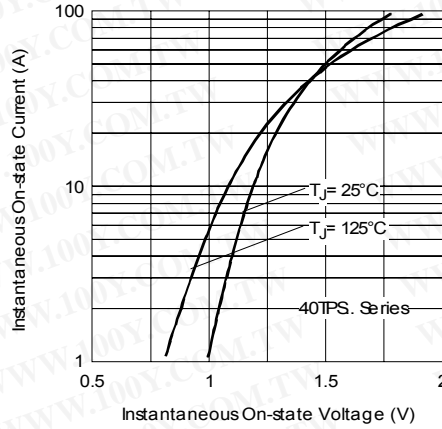


Fig. 7 - On-state Voltage Drop Characteristics

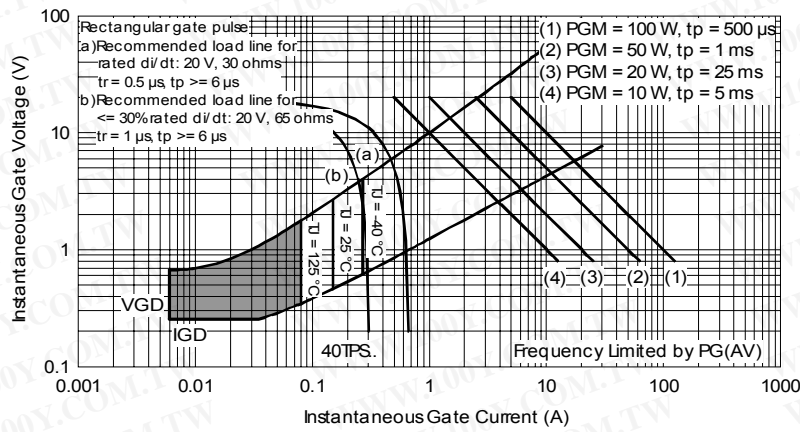


Fig. 8 - Gate Characteristics

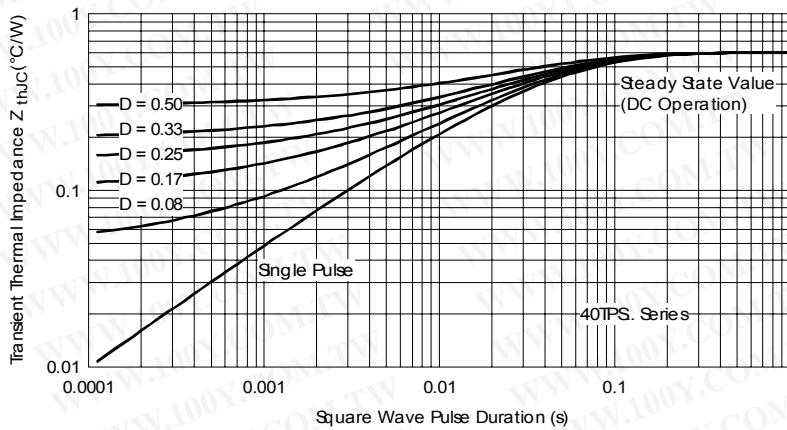


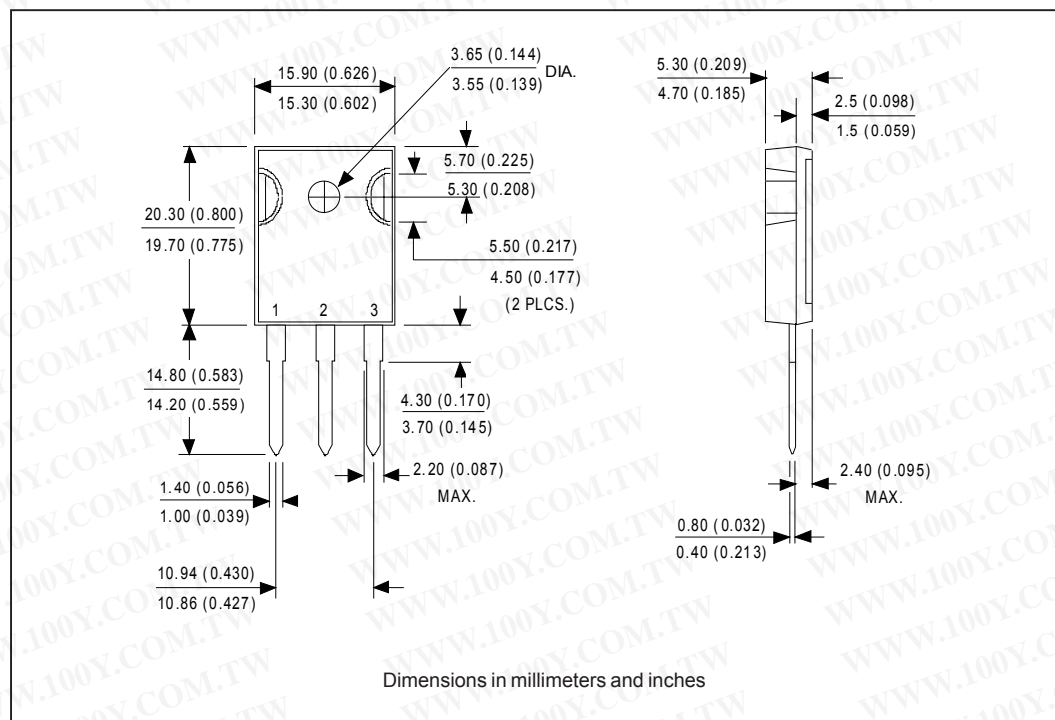
Fig. 9 - Thermal Impedance Z_{thJC} Characteristics

40TPS.. SAFEIR Series

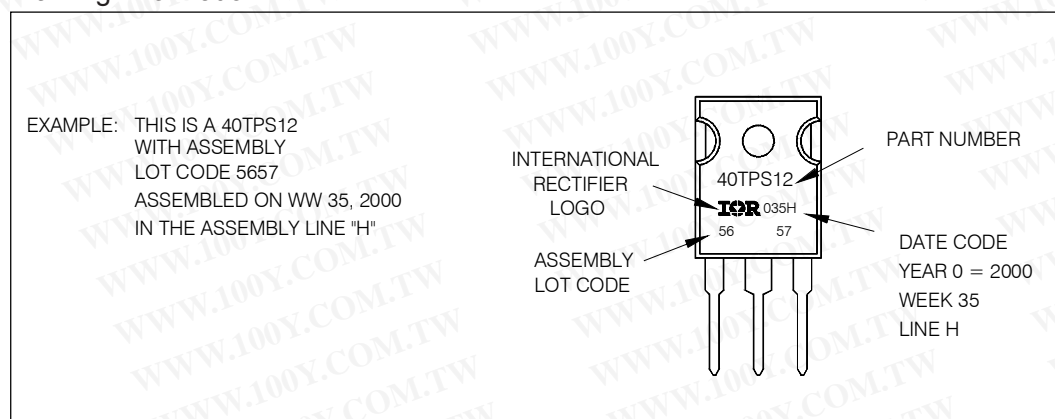
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Outline Table



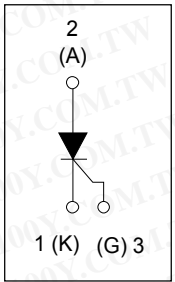
Marking Information



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Ordering Information Table

Device Code					
40	T	P	S	12	
①	②	③	④	⑤	⑥

<p>1 - Current Rating</p> <p>2 - Circuit Configuration: T = Thyristor</p> <p>3 - Package: P = TO-247</p> <p>4 - Type of Silicon: S = Standard Recovery Rectifier</p> <p>5 - Voltage code: Code x 100 = V_{RRM}</p> <p>6 - None = Standard Igt selection</p> <p style="background-color: yellow;">A = Low Igt selection 40mA max. for 40TPS08A and 40TPS12A</p>	
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08 = 800V
12 = 1200V

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Data and specifications subject to change without notice.
 This product has been designed and qualified for Industrial Level.
 Qualification Standards can be found on IR's Web site.